

L Number	Hits	Search Text	DB	Time stamp
18	1	("6004847").PN.	USPAT	2003/09/30 10:40
20	265	438/\$.ccls. and (ONS or (oxide adj nitride adj silicon) and (photoresist or resist or mask) and @ad<=20011130	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/30 11:11
21	150	438/\$.ccls. and (oxide adj nitride adj silicon) and (photoresist or resist or mask) and @ad<=20011130	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/30 10:58
22	100	438/\$.ccls. and (oxide adj nitride adj silicon) and (photoresist) and @ad<=20011130	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/30 10:58
23	21	438/\$.ccls. and ((oxide adj nitride adj silicon) same (photoresist)) and @ad<=20011130	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/30 11:08
24	13829	438/\$.ccls. and ((silicon) same (photoresist)) and @ad<=20011130	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/30 11:09
25	982	438/255,258,201,261,257,756,757,724.cccls. and ((silicon) same (photoresist)) and @ad<=20011130	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/30 11:09
19	13	438/255,258,201,261,257,756,757,724.cccls. and (ONS or (oxide adj nitride adj silicon) and (photoresist or resist or mask) and @ad<=20011130	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/30 11:11
26	3	438/255,258,201,261,257,756,757,724.cccls. and ((oxide adj nitride adj silicon) same (photoresist or resist or mask)) and @ad<=20011130	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/30 11:20
-	3	((("6004847") or ("5104819") or ("6274428")).PN.	USPAT	2003/09/30 10:40
-	524	(438/255).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:08
-	479	(438/258).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:10
-	271	(438/261).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:10
-	1104	(438/257).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:10
-	450	(438/756).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:11

-	23	((ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon))	USPAT; JPO	2003/04/07 12:38
-	0	((ONO or (oxide adj nitride adj oxide)) and (ONS or (oxide adj nitride adj silicon))) and (photoresist or mask) and (re-oxidiz\$6 or (second adj oxidiz\$6))	USPAT; JPO	2003/04/07 12:39
-	0	((ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon))) and (photoresist or mask) and (re-oxidiz\$6 or (second adj oxidiz\$6))	USPAT; JPO	2003/04/07 12:41
-	11	((ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon))) and (photoresist or mask) and semiconductor	USPAT; JPO	2003/04/07 12:40
-	22	((ONO or (oxide adj nitride adj oxide)) and (ONS or (oxide adj nitride adj silicon))) and (photoresist or mask) and semiconductor	USPAT; JPO	2003/04/07 12:40
-	36	((ONO or (oxide adj nitride adj oxide)) or (ONS or (oxide adj nitride adj silicon))) and (photoresist or mask) and (re-oxidiz\$6 or (second adj oxidiz\$6))	USPAT; JPO	2003/04/07 12:40
-	0	((ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon))) and (photoresist or mask) and (second adj oxidiz\$6)	USPAT; JPO	2003/04/07 12:41
-	0	((ONO or (oxide adj nitride adj oxide)) and (ONS or (oxide adj nitride adj silicon))) and (photoresist or mask) and (second adj oxidiz\$6)	USPAT; JPO	2003/04/07 12:41
-	10	("("5756376") or ("5770467") or ("6318267") or ("6004847") or ("6429470") or ("6180457") or ("5104819") or ("5572050") or ("6472259") or ("4775549")).PN.	USPAT	2003/04/08 09:24
-	1	("5650344").PN.	USPAT	2003/04/08 09:37
-	5	("("5650344") or ("4698787") or ("4543597") or ("5049514") or ("5083172")).PN.	USPAT	2003/04/08 09:38
-	8	("("6225162") or ("6388305") or ("6168987") or ("6133602") or ("5591681") or ("5436481") or ("6133093") or ("6096604")).PN.	USPAT	2003/04/18 13:51
-	9	("("6225162") or ("6388305") or ("6168987") or ("6133602") or ("5591681") or ("5436481") or ("6133093") or ("6096604") or ("5572050")).PN.	USPAT	2003/04/18 15:09